

### **INCHANGE SEMICONDUCTOR**

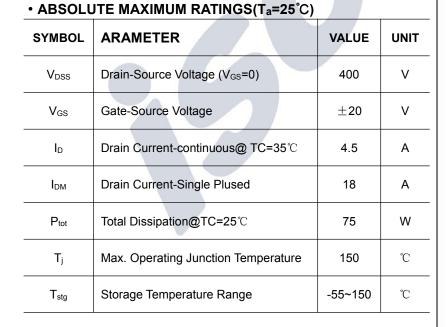
### isc N-Channel Mosfet Transistor

## BUZ60B

#### FEATURES

- 4.5A, 400V
- SOA is Power Dissipation Limited
- Nanosecond Switching Speeds
- Linear Transfer Characteristics
- High Input Impedance
- Majority Carrier Device
- Minimum Lot-to-Lot variations for robust device performance and reliable operation
- DESCRITION

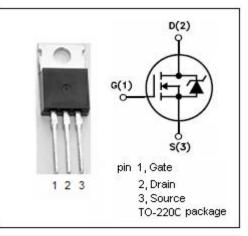
Designed for applications such as switching regulators, switching converters, motor drivers, relay drivers and drivers for high power bipolar switching transistors requiring high speed and low gate drive power.

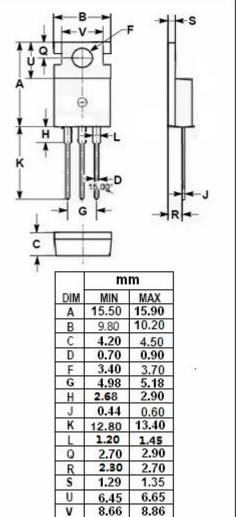


#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT	
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	1.67	°C/W	
Rth j-a	Thermal Resistance, Junction to Ambient	75	°C/W	

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#### isc website: www.iscsemi.com



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### **ELECTRICAL CHARACTERISTICS**

#### T<sub>c</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYPE	МАХ	UNIT
$V_{(BR)DSS}$	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> =0.25mA	400			V
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS}$ = $V_{GS}$ ; $I_D$ =1mA	2.1		4.0	V
V <sub>SD</sub>	Diode Forward On-voltage	I <sub>S</sub> = 9A ;V <sub>GS</sub> = 0			1.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> = 2.5A			1.5	Ω
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> = ±20V;V <sub>DS</sub> = 0			±100	nA
IDSS	Zero Gate Voltage Drain Current	V <sub>DS</sub> =400V; V <sub>GS</sub> = 0			250	μA
Gfs	Forward Transconductance	V <sub>DS</sub> = 25V; I <sub>D</sub> =2.5A	1.7			S
t <sub>d(on)</sub>	Turn-on Delay Time	V <sub>GS</sub> =10V;			45	
tr	Rise Time	I <sub>D</sub> =2.6A;			60	
$t_{d(off)}$	Turn-off Delay Time	V <sub>DD</sub> =30V; R <sub>GS</sub> =50 Ω			140	ns
t <sub>f</sub>	Fall Time				65	

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